

DIODE

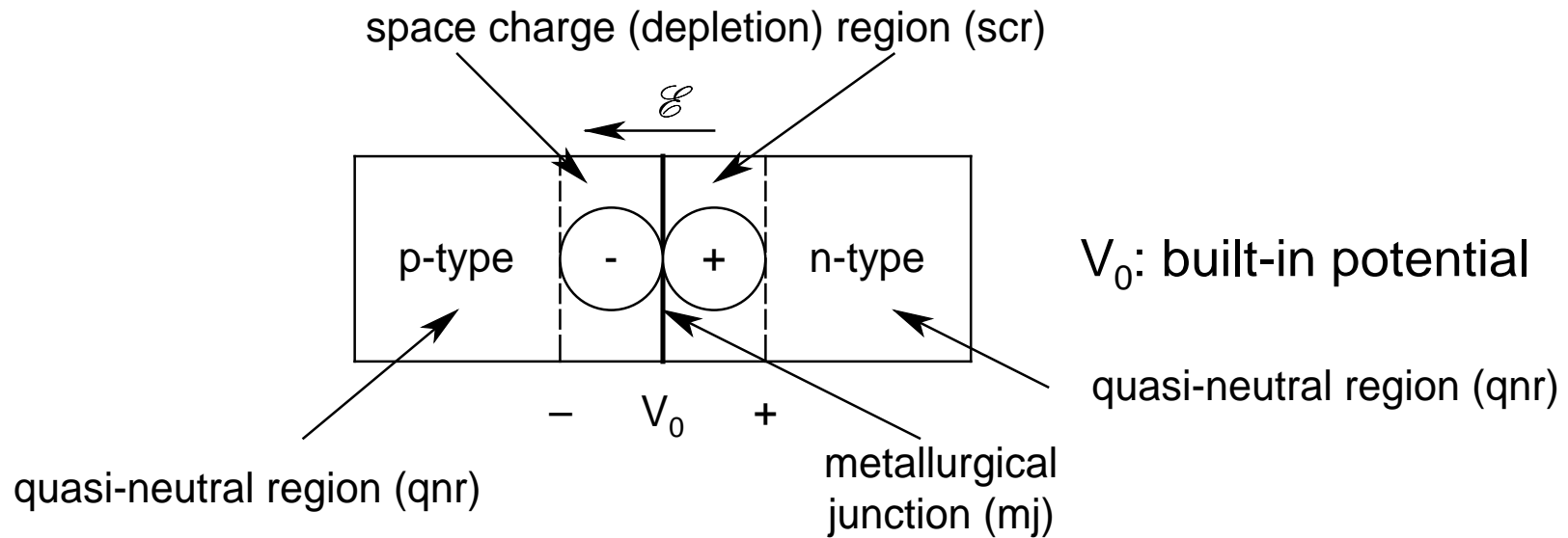
p-type
(N_A)

n-type
(N_D)

N_A : Acceptor Doping
 N_D : Donor Doping

Before Joining

- ***p-side***:
 - *Holes majority carriers*
 - *Electrons minority carriers*
- ***n-side***:
 - *Electrons majority carriers*
 - *Holes minority carriers*
- ***Holes***: *Anti-particles* of *electrons*



After Joining (In Equilibrium)

- ***Dissociation Relations:***

$$N_A \leftrightarrow N_A^- + \text{hole}$$

$$N_D \leftrightarrow N_D^+ + \text{electron}$$

Establishment of Equilibrium

- *Holes diffuse from p to n*
 - *Negatively charged acceptor ions uncovered near MJ*
- *Electrons diffuse from n to p*
 - **Positively charged donor ions uncovered near MJ**
- *Establishment of a charge dipole around MJ*
 - *Generation of an electric field \mathcal{E} around MJ*
 - *Creation of built-in potential V_0*